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TABLE OF CONTENTS

Tunable Inductive Output Matching for W-Band Power Amplifier	1
<i>Isabel Kraus, Herbert Knapp, Nils Pohl</i>	
Optimization Methodology for Wideband SLMBA Design Considering Balanced Amplifiers' Off-State Impedance	5
<i>Wang Liu, Luís C. Nunes, Filipe M. Barradas, José C. Pedro, Qiang Liu</i>	
Design of a 3.5 GHz Symmetric Doherty PA in an 8-Inch GaN on Silicon MMIC Technology for Base Station Applications.....	9
<i>Dhruvin Dhaval Pandya, Christian Schuberth, Sudip Ghosh, Minghao Koh, Helmut Brech, Rüdiger Quay</i>	
Automated On-Wafer Radio-Frequency Transistor Characterization with Adaptive Probing and Features Extraction with Uncertainties.....	13
<i>Alessandro Chillico, Domenico Vitali, Wojciech Samek, Olof Bengtsson</i>	
Temperature and Concentration Retrieval in Microwave Dielectric Spectroscopy Using a Two-Tier Machine Learning Framework	17
<i>Maede Chavoshi, Sevda Seyyedmasoumian, Yan Zheng, Guy A. E. Vandenbosch, Bart Nauwelaers, Tomislav Markovic, Dominique Schreurs</i>	
Temperature-Dependent Vector-Calibrated Large-Signal Measurements of a GaN-Based SPDT Ka-Band Switch	20
<i>Dashiel Matlock, Dave Frey, Matt Hodek, Nicholas C. Miller, Edward Gebara</i>	
A Ku-Band GaN PA with GaAs Gate Modulator for Improved Linearity.....	24
<i>Reyes Lucero, Zoya Popovic</i>	
Fast Optimization of RF Power Transistors with mmWave Active Load-Pull Techniques	28
<i>Christoph Schulze, Wolfgang Heinrich, Olof Bengtsson</i>	
A 200/400 GHz Cascode SiGe Voltage-Controlled Oscillator Exploiting Harmonic Optimization Technique for mmWave Applications.....	32
<i>Mehran Khanehbeygi, Giorgio Tatangelo, Leonardo Pantoli, Giorgio Leuzzi</i>	
Enhancement of mmW Detection Using Dual-Terminal Excitation in Transistors	35
<i>Philippe Artillan, Gaudencio Paz-Martinez, Edouard Rochefeuille, Héctor Sánchez-Martín, Sergio García-Sánchez, Tomás González, Javier Mateos, Ignacio Iñiguez-De-La-Torre</i>	
Impact on Linearity of a Wideband Design Strategy for an Integrated GaN Doherty Power Amplifier.....	39
<i>Giulia Bartolotti, Anna Piacibello, Vittorio Camarchia</i>	
A PA Model for Fast Linearity and Efficiency Evaluation Under Modulated Signal Excitations	43
<i>Filipe M. Barradas, Luís C. Nunes, Pedro M. Cabral</i>	
Analysis and Development of a Two RF Input Load Modulated Envelope Tracking PA.....	47
<i>Alessandro Cidronali, Monica Righini, Marco Badii, Lorenzo Pagnini, Giovanni Lasagni, Giovanni Collodi</i>	
On the Implementation of Capacitance Models in Electronic Computer-Aided Design Tools	51
<i>Ilcho Angelov, Christian Fager, Niklas Rorsman</i>	

High-Efficiency C/X Dual-Band HPA in 250-Nm Gate Length GaN HEMT Technology with 10W Pout.....	55
<i>Filippo Bolli, Patrick E. Longhi, Sergio Colangeli, Alessio Pantellini, Giorgio Polli, Mario Castorio, Walter Ciccognani, Antonio Serino, Ernesto Limiti</i>	
Cardiff Behavioral Model of a Ka-Band SPDT Switch Trained on Structured Minimization of Load-Pull Characterization Data	59
<i>Seyed Urman Ghozati, Ehsan Merhabi Azad, Kauser Chaudhry, Roberto Quaglia, Paul J. Tasker</i>	
A 10 W C-Ku Band MMIC NDPA for Electronic Warfare Applications.....	63
<i>Andrea Forte, Patrick Ettore Longhi, Sergio Colangeli, Walter Ciccognani, Alessio Pantellini, Giorgio Polli, Mario Castorio, Ernesto Limiti</i>	
A Design Method for Wide Bandwidth Reflective Analog Predistorters	67
<i>Jiayang Yu, Inês Pinto, Filipe M. Barradas, Luís C. Nunes, Telmo R. Cunha, José C. Pedro</i>	
A Knowledge-Based Transfer Learning Capacitance Model for GaN HEMTs.....	71
<i>Lei Huang, Shuman Mao, Huanpeng Wang, Qingzhi Wu, Min Tang, Yuehang Xu</i>	
A 10 W GaN/Si Doherty Power Amplifier Designed for 15 GHz 6G Band with 8 dB Backoff Efficiency	75
<i>Hossein Zaheri, Rob Vissers, Han Zhou, Gregor Lasser</i>	
Digital Self-Interference Cancellation for In-Band Full-Duplex Communications.....	79
<i>Amirmohammad Shahghasi, Raúl Criado, Gabriel Montoro, Pere L. Gilabert</i>	
Exploring Software-Defined Radio Based Noise Measurements: Performances Analysis and Opportunities	82
<i>Giacomo Schiavolini, Giulia Orecchini, Valentina Palazzi, Paolo Mezzanotte, Luca Roselli, Federico Alimenti</i>	
Design of Multi-Octave RF PA Based on PSO Method with Individually Self-Adaptive Hyperparameters	85
<i>Benhao Jin, Giovanni Crupi, Jialin Cai</i>	
Impact of Incomplete Conversion Data Extraction on Large-Signal Stability Analysis.....	88
<i>Sergio Colangeli, Walter Ciccognani, Patrick E. Longhi, Antonio Serino, Ernesto Limiti</i>	
A 10 W Ultra-Wideband MMIC HPA for EW Applications.....	92
<i>Giulio Venanzoni, Andrea Forte, Patrick E. Longhi, Sergio Colangeli, Antonio Serino, Walter Ciccognani, Alessio Pitaro, Danilo Mercuri, Ernesto Limiti</i>	
Towards Quantifying Two-Mode Correlation Linewidths in Quantum Circuits	96
<i>Alessandro Alocco, Andrea Celotto, Luca Fasolo, Bernardo Galvano, Emanuele Palumbo, Luca Oberto, Luca Callegaro, Felice Francesco Tafuri, Patrizia Livreri, Emanuele Enrico</i>	
Transformer Based Waveform Engineered Power Amplifier in a 65 nm Bulk-CMOS Process.....	100
<i>Praveen Saraswat, Mahima Arrawatia</i>	
Evaluation of Trapping Dynamics in GaN HEMTs from Double-Pulse RF Load-Pull Measurements.....	103
<i>Matteo Tiberi, Alberto M. Angelotti, Gian Piero Gibiino, Gustavo Avolio, Mauro Marchetti</i>	
A Behavioral Approach to Equivalent-Circuit Modeling of GaN MMIC Varactor Cells.....	107
<i>Simone Cangini, Alberto M. Angelotti, Gian Piero Gibiino, Corrado Florian, Alberto Santarelli</i>	

Experimental Characterization of VSWR-Adaptive Balanced Power Amplifiers	111
<i>Carbonnière Alexis, Bacqué Ludovic, Medrel Pierre, Nébus Jean-Michel</i>	
Highly Efficient and Linearity-Enhanced S-Band Doherty Power Amplifier	114
<i>Giulia Bartolotti, Zhifan Zhang, Anna Piacibello, Vittorio Camarchia</i>	
Characterization and Modeling of Dual-Input Doherty Power Amplifier for High Efficiency and Bandwidth	118
<i>Gabriele Basaglia, Han Zhou, Gianni Bosi, Valeria Vadalà, Antonio Raffo, Giorgio Vannini, Christian Fager</i>	
Non-Linear Microwave Transistor Modeling Through ANNs: A Frequency-Domain CAD Implementation.....	121
<i>Chiara Ramella, Simona Donati Guerrieri, Simone Corbellini, Marco Pirola</i>	
An Example of the Role of Time-Modulated Capacitances in Microwave Time-Varying Systems	124
<i>Teresa M. Martín-Guerrero, Tomás A. Lira-Valdés, Elena Abdo-Sánchez</i>	
Characterization Procedure for Effective Evaluation of III-V Compound Semiconductor Technology	127
<i>Negar Choupan, Valeria Vadalà, Gianni Bosi, Chiara Ramella, Marco Grassi, Giovanni Crupi, Rocco Giofrè, Antonio Raffo, Giorgio Vannini</i>	
Design and Simulation of a Doherty-Mode OLMBA for Enhanced Back-Off Efficiency Over an Octave Bandwidth	131
<i>Jean-Baptiste Urvoy, Roberto Quaglia, Steve C. Cripps</i>	
Assessment of Dynamic Deviation Reduction-Based Volterra Modeling and Digital Predistortion of RF Passive Doubler	135
<i>Ali H. Alsarraf, Gian Piero Gibiino, Dominique Schreurs</i>	
Improved Iterative Envelope Simulation for the Efficient Prediction of the Impact of Wideband Modulated Signals on Power Amplifier Performance	139
<i>Indy Van Den Heuvel, Roberto Quaglia, Steve C. Cripps, Paul J. Tasker</i>	
Sparse Volterra-Based Models for I/Q Impairments and Nonlinear Distortion of Power Amplifiers.....	143
<i>María J. Madero-Ayora, Juan A. Becerra, Elías Marqués-Valderrama, Carlos Crespo-Cadenas</i>	
A Simple Lumped-Element Topology for Wideband Class-E Operation at UHF and L Bands.....	147
<i>Pablo Olmedillo, Andrés González, Mostapha Ouadefli, José A. García</i>	
A GaN-On-SiC Transmit/Receive MMIC Frontend for 6-To-18-GHz Phased Array Transceivers	151
<i>Marta Ferreras, Jesús Grajal</i>	
MMIC Power Amplifier in GaAs HBT Technology for Wi-Fi 6 Applications.....	155
<i>Chiara Ramella, Corrado Florian, Francesco Manni, Alberto Maria Angelotti, Gian Piero Gibiino, Rocco Giofrè, Marco Pirola, Paolo Colantonio</i>	
Load/Source-Pull Evaluation of Modulated Performance in GaAs HBT Power Cells for WiFi-6.....	159
<i>Alberto Maria Angelotti, Corrado Florian, Gian Piero Gibiino, Chiara Ramella, Marco Pirola, Francesco Manni, Rocco Giofrè, Paolo Colantonio</i>	
A Two-Octave GaN Power Amplifier Based on a Multi-Section Chebyshev Transformer	163
<i>Reza Koliaei, Giulia Bartolotti, Zhifan Zhang, Anna Piacibello, Vittorio Camarchia</i>	

Author Index